

#### Positive Fixed 5V Voltage Regulator in bare die form

Rev 1.1 20/12/17

#### Description

The 78L05AC is a 5V fixed 3-terminal voltage regulator delivering up to 100mA of output current and equipped with internal limiting + thermal shutdown features for overload immunity. Implementing this device at point-of-source removes the complexity of single point regulation methods with reduced noise. Used in replacement of a Zener diode/resistor combination, the device improves output impedance by x2 order of magnitude and delivers lower bias current with lower noise. The device can also be used with power-pass elements to make high-current voltage regulators.

#### **Ordering Information**

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-PRF-883 /2010B Visual Inspection+ MIL-STD-38534 Class H LAT
- "K" MIL-PRF-883 /2010A Visual Inspection (Space)
  + MIL-STD-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

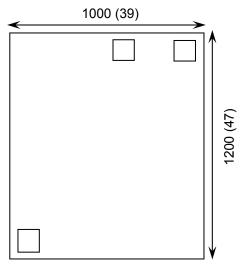
### **Supply Formats:**

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- With Ti/Ni/Ag Back Metal On request
- In Metal or Ceramic package On request

#### Features:

- ±5% V<sub>OUT</sub> tolerance over entire temperature range
- 100mA Output Current
- Internal thermal overload protection
- Internal short circuit current limit
- Full Military Temperature Range
- Negative Voltage complement is 79L05

### Die Dimensions in µm (mils)



### **Mechanical Specification**

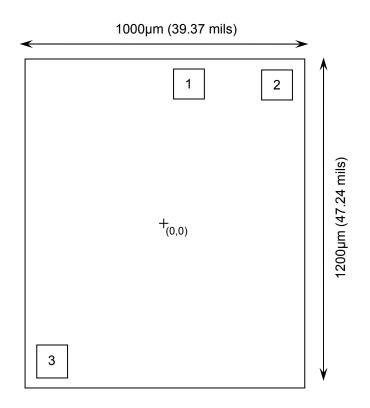
Die Size (Unsawn)	1000 x 1200 39.37 x 47.24	µm mils	
Minimum Bond Pad Size	110 x 105 4.33 x 4.13	µm mils	
Die Thickness	280 (±20) 11 (±0.8)	μm mils	
Top Metal Composition	Al 1%Si 1.4μm		
Back Metal Composition	N/A – Bare Si		





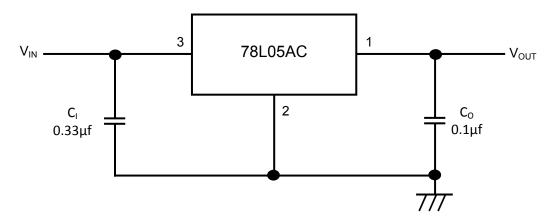
Rev 1.1 20/12/17

### Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
		X	Y		
1	VOUT	30	410		
2	VIN	312	407		
3	GND	-412	-508		
CONNECT CHIP BACK TO GND					

### **Typical Application**



 $C_l$  is required if the regulator is located an appreciable distance from power supply filter.  $C_O$  is not required for stability; however it does improve transient response. For optimum stability and transient response locate  $C_l$   $C_O$  as close as possible to the regulator.





Rev 1.1 20/12/17

### Absolute Maximum Ratings T<sub>A</sub> = 125°C unless otherwise stated

PARAMETER	SYMBOL	VALUE	UNIT
Input Voltage	V <sub>IN</sub>	30	V
Power Dissipation <sup>1</sup>	P <sub>D</sub>	620	mW
Operating Temperature Range	-	-55 to 125	°C
Maximum Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C

### Operating Conditions T<sub>A</sub> = 125°C unless otherwise stated

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V <sub>IN</sub>	7	20	V
Output Current	I <sub>OUT</sub>	-	100	mA
Operating Temperature Range	-	-55 to 125		°C

### DC Electrical Characteristics, V<sub>i</sub> =10V, I<sub>OUT</sub>=40mA,C<sub>i</sub>=0.3µF, C<sub>o</sub>=0.1µf, 0°C<T<sub>J</sub><+125°C(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage	V <sub>OUT</sub>	$T_J = 25^{\circ}C, I_O = 40 \text{mA}$	4.80	5.00	5.20	V
		$1\text{mA} \le I_{\text{OUT}} \le 40\text{mA}, 7\text{V} \le V_{\text{IN}} \le 20\text{V}$	4.75	5.00	5.25	
		$1\text{mA} \le I_{\text{OUT}} \le 70\text{mA}, V_{\text{IN}} = 10\text{V}$	4.75	5.00	5.25	
Line Regulation	$\Delta V_{OUT}$	$7V \le V_{IN} \le 20V$ , $T_J = 25$ °C, $I_O = 40$ mA	-	32	150	mV
	A V 001	8V ≤ V <sub>IN</sub> ≤ 20V, T <sub>J</sub> = 25°C, I <sub>O</sub> =40mA	-	26	100	
Load Regulation	ΔV <sub>OUT</sub>	$1\text{mA} \le I_{\text{OUT}} \le 100\text{mA}, T_{\text{J}} = 25^{\circ}\text{C}$	-	15	60	
		1mA ≤ I <sub>OUT</sub> ≤ 40mA, T <sub>J</sub> = 25°C	-	8	30	
Input Bias Current	I <sub>B</sub>	T <sub>J</sub> = 25°C	-	3.8	6.0	mA
		T <sub>J</sub> = 125°C	-	-	5.5	
Input Bias Current	$\Delta I_{B}$	9V ≤ V <sub>IN</sub> ≤ 20V	-	-	1.5	mA
Change	ΔIB	1mA ≤ I <sub>OUT</sub> ≤ 40mA	-	-	0.1	ША
Output Noise Voltage	e <sub>N</sub>	10Hz ≤ f ≤ 100KHz, T <sub>A</sub> = 25°C	-	42	-	$\mu V_{\text{RMS}}$
Ripple Rejection	RR	f = 120Hz, 8V ≤ V <sub>IN</sub> ≤ 20V, T <sub>J</sub> = 25°C	41	49	-	dB
Dropout Voltage	V <sub>D</sub>	V <sub>IN</sub> -V <sub>OUT</sub>	-	1.7	-	V

Notes: **1.** Value measured in TO-92 package applicable only for DC power dissipation permitted by absolute maximum ratings. Results in die form are dependent on die attach and assembly method.





Rev 1.1 20/12/17

DISCLAIMER: The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Silicon Supplies Ltd hereby disclaims any and all warranties and liabilities of any kind.

LIFE SUPPORT POLICY: Silicon Supplies Ltd components may be used in life support devices or systems only with the express written approval of Silicon Supplies Ltd, if a failure of such components can reasonably be expected to cause the failure of that life support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

